Quad. Bus Buffer Gates with 3-state Outputs

REJ03D0499–0200 Rev.2.00 Dec. 10, 2004

Description

The RD74LVC126B has four bus buffer gates in a 14 pin package. The device requires the three state control input OE to be taken low to put the output into the high impedance condition. Low voltage and high-speed operation is suitable at the battery drive product (note type personal computer) and low power consumption extends the life of a battery for long time operation.

Features

- $V_{CC} = 1.65 \text{ V}$ to 5.5 V
- All inputs V_{IH} (Max.) = 5.5 V (@V_{CC} = 0 V to 5.5 V)
- All outputs V_{OUT} (Max.) = 5.5 V (@V_{CC} = 0 V or output off state)
- Typical V_{OL} ground bounce < 0.8 V (@V_{CC} = 3.3 V, Ta = 25°C)
- Typical V_{OH} undershoot > 2.0 V (@V_{CC} = 3.3 V, Ta = 25°C)
- High output current $\pm 4 \text{ mA} (@V_{CC} = 1.65 \text{ V})$

 $\begin{array}{l} \pm 8 \mbox{ mA } (@V_{CC} = 2.3 \mbox{ V}) \\ \pm 12 \mbox{ mA } (@V_{CC} = 2.7 \mbox{ V}) \\ \pm 24 \mbox{ mA } (@V_{CC} = 3.0 \mbox{ V to } 5.5 \mbox{ V}) \end{array}$

• Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
RD74LVC126BFPEL	SOP-14 pin (JEITA)	FP–14DAV	FP	EL (2,000 pcs/reel)
RD74LVC126BTELL	TSSOP-14 pin	TTP-14DV	Т	ELL (2,000 pcs/reel)

Function Table

Inp		
OE	Outputs Y	
L	Х	Z
Н	L	L
Н	Н	Н

H: High level

L: Low level

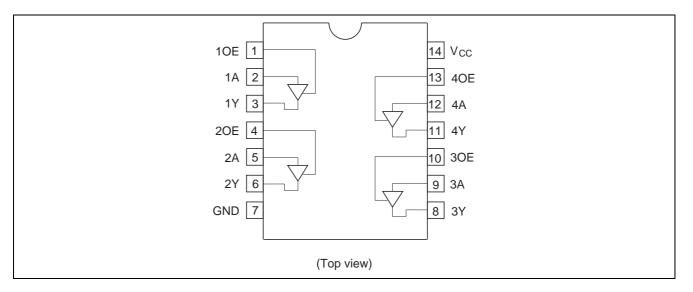
X: Immaterial

Z: High impedance



Pin Arrangement

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Absolute Maximum Ratings

ltem	Symbol	Ratings	Unit	Conditions
Supply voltage	V _{cc}	–0.5 to 7.0	V	
Input diode current	I _{IK}	-50	mA	$V_1 = -0.5 V$
Input voltage	VI	–0.5 to 7.0	V	
Output diode current	I _{ок}	-50	mA	$V_{O} = -0.5 V$
		50		$V_{O} = V_{CC}$ +0.5 V
Output voltage	Vo	–0.5 to V _{CC} +0.5	V	Output "H" or "L"
		–0.5 to 7.0		Output "Z" or V _{CC} : OFF
Output current	lo	±50	mA	
V _{CC} , GND current / pin	I _{CC} or I _{GND}	±100	mA	
Storage temperature	Tstg	–65 to +150	°C	

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.



Recommended Operating Conditions

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Item	Symbol	Ratings	Unit	Conditions
Supply voltage	upply voltage V _{CC} 1.5 to 5.4		V	Data hold
		1.65 to 5.5		At operation
Input / output voltage	VI	0 to 5.5	V	
	Vo	0 to V _{CC}	V	Output "H" or "L"
		0 to 5.5		Output "Z" or V _{CC} : OFF
Operating temperature	Та	-40 to 85	°C	
Output current	I _{OH}	-4	mA	V _{CC} = 1.65 V
		-8		V _{CC} = 2.3 V
		-12		$V_{CC} = 2.7 V$
		-24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
	I _{OL}	4	mA	V _{CC} = 1.65 V
		8		V _{CC} = 2.3 V
		12		V _{CC} = 2.7 V
		24		$V_{CC} = 3.0 \text{ V to } 5.5 \text{ V}$
Input rise / fall time *1	t _r , t _f	20	ns/V	$V_{CC} = 1.65 \text{ V to } 2.7 \text{ V}$
		10		V_{CC} = 3.0 V to 5.5 V

Note: 1. This item guarantees maximum limit when one input switches. Waveform: Refer to test circuit of switching characteristics.



Electrical Characteristics

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			Ta = -40 to 85°C			
Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	VIH	1.65 to 1.95	V _{CC} ×0.65		V	
		2.3 to 2.7	1.7			
		2.7 to 3.6	2.0			
		4.5 to 5.5	V _{CC} ×0.7			
	VIL	1.65 to 1.95	—	$V_{CC} \!\!\times\!\! 0.35$	V	
		2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
		4.5 to 5.5	—	V _{CC} ×0.3		
Output voltage	V _{OH}	1.65 to 5.5	V _{CC} -0.2		V	I _{OH} = -100 μA
		1.65	1.2	_		$I_{OH} = -4 \text{ mA}$
		2.3	1.7	_		I _{OH} = -8 mA
		2.7	2.2			I _{OH} = -12 mA
		3.0	2.4			
		3.0	2.2	_		I _{OH} = -24 mA
		4.5	3.8			
	V _{OL}	1.65 to 5.5	—	0.2	V	I _{OL} = 100 μA
		1.65	—	0.45		I _{OL} = 4 mA
		2.3	—	0.7		I _{OL} = 8 mA
		2.7	—	0.4		I _{OL} = 12 mA
		3.0	—	0.55		I _{OL} = 24 mA
		4.5	—	0.55		
Input current	I _{IN}	0 to 5.5	—	±5.0	μA	$V_{IN} = 5.5 \text{ V} \text{ or GND}$
Output leak current	I _{OFF}	0	—	±5.0	μA	V_{IN} / V_{OUT} = 5.5 V
Off state output current	loz	2.7 to 5.5	—	±5.0	μA	$V_{IN} = V_{CC}$ or GND,
						$V_{OUT} = 5.5 V \text{ or GND}$
Quiescent supply current	I _{CC}	2.7 to 3.6	—	±5.0	μΑ	V_{IN} = 3.6 V to 5.5 V
		2.7 to 5.5	—	5.0		$V_{IN} = V_{CC}$ or GND
	ΔI_{CC}	2.7 to 3.6		500	μA	V_{IN} = one input at (V _{CC} –0.6) V, other inputs at V _{CC} or GND



Switching Characteristics

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			Ta = -40 to 85°C				From	То
ltem	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	(Input)	(Output)
Propagation delay time	t _{PLH}	1.8±0.15	1.0	—	9.8	ns	А	Y
	t _{PHL}	2.5±0.2	1.0	—	7.2			
		2.7	1.0	—	5.2			
		3.3±0.3	1.0	—	4.7			
		5.0±0.5	1.0	—	3.7			
Output enable time	t _{ZH}	1.8±0.15	1.0	—	10.0	ns	OE	Y
	t _{ZL}	2.5±0.2	1.0	_	8.3			
		2.7	1.0	_	6.3			
		3.3±0.3	1.0	_	5.7			
		5.0±0.5	1.0	_	4.7			
Output disable time	t _{HZ}	1.8±0.15	1.0	_	12.6	ns	OE	Y
	t _{LZ}	2.5±0.2	1.0	—	8.7			
		2.7	1.0	—	6.7			
		3.3±0.3	1.3	_	6.0			
		5.0±0.5	1.0	—	5.0			
Between output pins skew *1	t _{OSLH}	1.8±0.15	—	—	—	ns		
	t _{OSHL}	2.5±0.2	_	—	—			
		2.7	—	—	—			
		3.3±0.3	—	—	1.0]		
		5.0±0.5	—	—	1.0]		
Input capacitance	CIN	3.3	—	4.0	—	pF		
Output capacitance	Co	3.3	_	7.0	—	pF		

Note: 1. This parameter is characterized but not tested.

 $\text{tos}_{\text{LH}} = \mid t_{\text{PLHm}} \text{-} t_{\text{PLHn}} \mid \text{, tos}_{\text{HL}} = \mid t_{\text{PHLm}} \text{-} t_{\text{PHLn}} \mid$

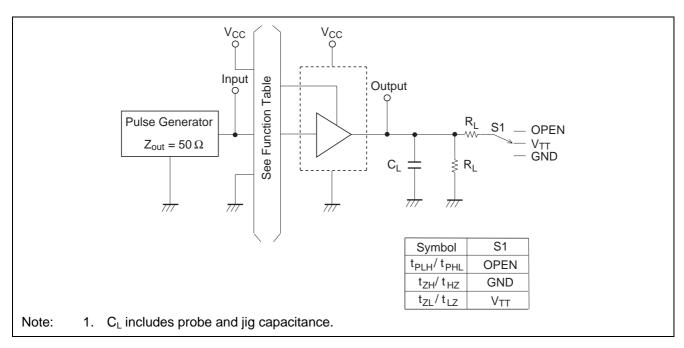
Operating Characteristics

 $Ta = 25^{\circ}C$

Item	Symbol	V _{cc} (V)	Min	Тур	Max	Unit	Test conditions
Power dissipation	CPD	1.8	_	21	—	pF	f = 10 MHz
capacitance		2.5	—	22	—		
		3.3	—	23	—		
		5.0	_	27	—		

Test Circuit

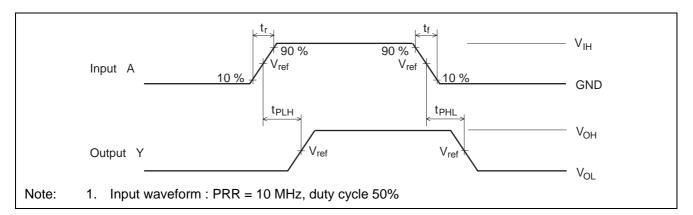
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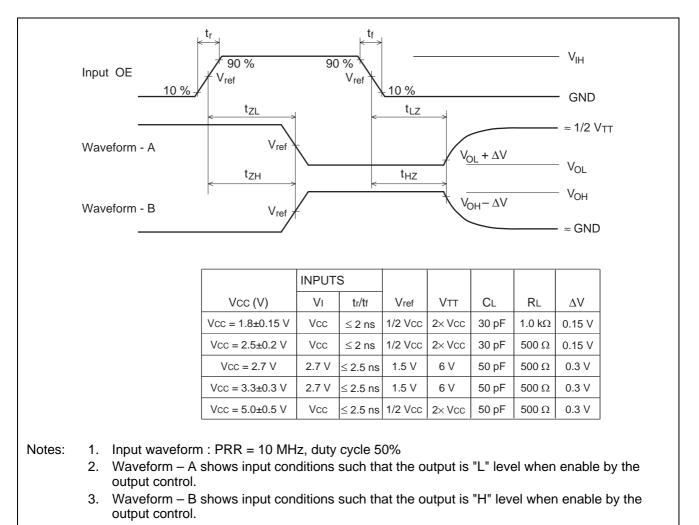


Waveforms - 1

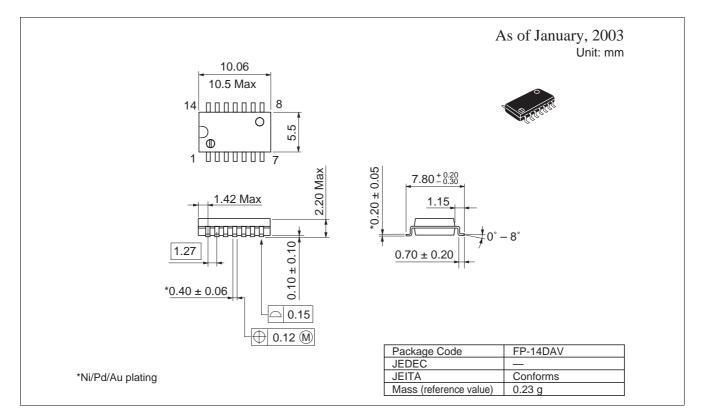
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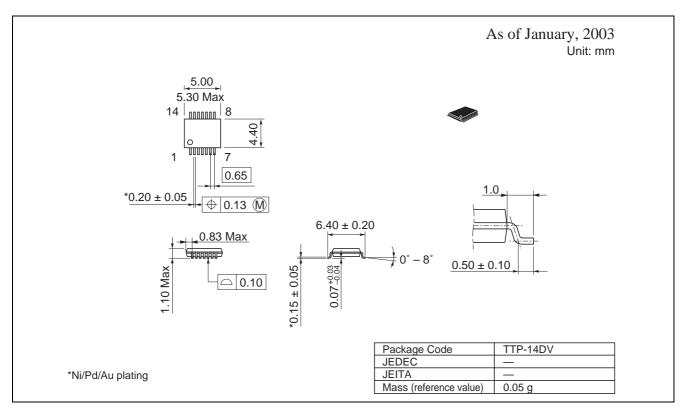


Waveforms – 2



Package Dimensions







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